UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/596,126	05/31/2006	Euijoon Yoon	21302/0204309-US0	2554
7278 DARBY & DA	7590 12/16/200 RBY P.C.	EXAMINER		
P.O. BOX 770	4.44	CRAWFORD, LATANYA N		
Church Street Station New York, NY 10008-0770			ART UNIT	PAPER NUMBER
			2813	
			MAIL DATE	DELIVERY MODE
			12/16/2009	PAPER

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

	Application No.	Applicant(s)		
	10/596,126	YOON ET AL.		
Office Action Summary	Examiner	Art Unit		
	LATANYA CRAWFORD	2813		
The MAILING DATE of this communication app Period for Reply	ears on the cover sheet with the c	orrespondence address		
A SHORTENED STATUTORY PERIOD FOR REPLY WHICHEVER IS LONGER, FROM THE MAILING DA  - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication.  - If NO period for reply is specified above, the maximum statutory period w  - Failure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICATION 36(a). In no event, however, may a reply be tim vill apply and will expire SIX (6) MONTHS from cause the application to become ABANDONE	N. nely filed the mailing date of this communication. D (35 U.S.C. § 133).		
Status				
Responsive to communication(s) filed on <u>03 Au</u> This action is <b>FINAL</b> . 2b)⊠ This     Since this application is in condition for allowar closed in accordance with the practice under E	action is non-final. nce except for formal matters, pro			
Disposition of Claims				
4) ☐ Claim(s) 1-23 is/are pending in the application. 4a) Of the above claim(s) 1-10 and 16 is/are wit 5) ☐ Claim(s) is/are allowed. 6) ☐ Claim(s) 11-15 and 17-23 is/are rejected. 7) ☐ Claim(s) is/are objected to. 8) ☐ Claim(s) are subject to restriction and/or Application Papers 9) ☐ The specification is objected to by the Examine 10) ☐ The drawing(s) filed on 31 May 2006 is/are: a)	thdrawn from consideration.  r election requirement.  r.	by the Examiner.		
Applicant may not request that any objection to the orection Replacement drawing sheet(s) including the correction 11). The oath or declaration is objected to by the Expression 11.	ion is required if the drawing(s) is obj	ected to. See 37 CFR 1.121(d).		
Priority under 35 U.S.C. § 119				
12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).  a) □ All b) □ Some * c) ☑ None of:  1. ☑ Certified copies of the priority documents have been received.  2. □ Certified copies of the priority documents have been received in Application No  3. □ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).  * See the attached detailed Office action for a list of the certified copies not received.				
Attachment(s)  1) Notice of References Cited (PTO-892)  2) Notice of Draftsperson's Patent Drawing Review (PTO-948)  3) Information Disclosure Statement(s) (PTO/SB/08) Paper No(s)/Mail Date 09/15/2009.	4)  Interview Summary Paper No(s)/Mail Da 5)  Notice of Informal P 6)  Other:	nte		

Application/Control Number: 10/596,126 Page 2

Art Unit: 2813

### **DETAILED ACTION**

1. This office action is in response to the correspondence filed on 08/03/2009. Currently, claims 11-15 & 17-23 are pending. Claims 1-10 are withdrawn.

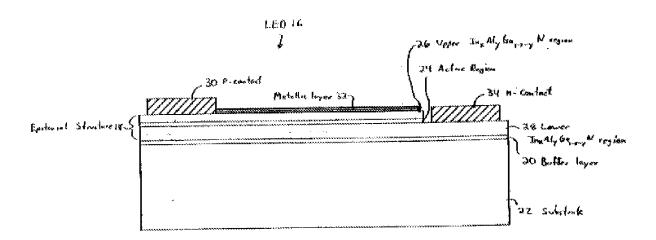
# Claim Rejections - 35 USC § 102

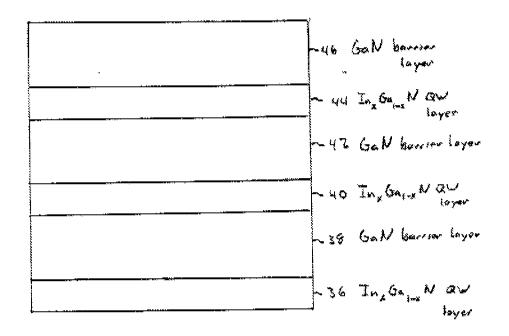
2. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- 3. Claims 11,12,14,15 &17-23 are rejected under 35 U.S.C. 102(b) as being anticipate by Bour (US Pub no. 2003/0020085 A1).

Pigure I





Regarding claim 11, Bour et al. discloses a nitride semiconductor light emitting device comprising: a substrate; at least one nitride semiconductor layer grown on the substrate (22)and including a top layer (28) of AlxGayIn1-x-yN ( $0 \le x \le 1$ ,  $0 < y \le 1$ ,  $0 < x + y \le 1$ ) a single quantum well layer (40) grown on the top layer of AlxGayIn1-x-yN ( $0 \le x \le 1$ ,  $0 < y \le 1$ ,  $0 < x + y \le 1$ ) with the top layer of AlxGayIn1-x-yN ( $0 \le x \le 1$ ,  $0 < y \le 1$ ,  $0 < x + y \le 1$ ) being mainly supplied from the top layer of AlxGayIn1-x-yN ( $0 \le x \le 1$ ,  $0 < y \le 1$ ,  $0 < x + y \le 1$ ) an additional nitride semiconductor layer (26) grown on the In-rich InGaN quantum well layer and having a band gap energy higher than that of the In-rich InGaN quantum well layer (since the quantum well layer is graded where both of the quantum well interfaces have indium concentration near zero [0041-0042] the top layer will have a higher bandgap in view of [0021]); wherein the In-rich InGaN quantum well layer comprises, an

In-rich region, a first compositional grading region with In content increasing between the top layer of AlxGayIn1-x-yN ( $0 \le x \le 1$ ,  $0 < y \le 1$ ,  $0 < x + y \le 1$ )second compositional grading region with In content decreasing between the In-rich region and the additional nitride semiconductor layer [0041].

Regarding claim 12, Bour et al. discloses wherein the quantum well layer is formed of  $In_xGa_{1-x}N$  and x in the In-rich region of the quantum well layer is equal to or more than 0.6 [0003][0041][0045].

Regarding claim 14, Bour et al. discloses wherein the quantum well layer is formed of  $In_xGa_{1-x}N$  and x in the In-rich region of the quantum well layer is within a range of 0.5 to 0.8 [0003][0041][0045].

Regarding claim 15, Bour et al. discloses wherein the thickness of the quantum well is equal to or less than 2nm [0026].

Regarding claim 17, Bour et al. discloses wherein the additional nitride (26) semiconductor is formed of AlyGayIn1-yN ( $0 \le y \le 1$ ) fig. 2.

Regarding claim 18, Bour et al. discloses further comprising at least one barrier layer (38)of layer AlyGayIn1-yN ( $0 \le y \le 1$ ) and having a band gap energy higher than that of the additional nitride semiconductor layer fig.3 in view of [0021].

Regarding claim 19, Bour et al. discloses wherein the at least one barrier layer of AlyGayIn1-yN ( $0 \le y \le 1$ ) [0026].

Regarding claim 20, Bour et al. discloses wherein the quantum well layer (40) and the at least barrier layer (38) of AlyGayIn1-yN ( $0 \le y \le 1$ ) form a multi-quantum well structure fig. 3.

Regarding claim 21, Bour et al. discloses wherein the pairs of the quantum well and the at least barrier layer of AlyGayIn1-yN ( $0 \le y \le 1$ ) to or less than 100 pairs fig.3.

Regarding claim 22, Bour et al. discloses the top layer of AlxGayIn1-x-yN ( $0 \le x \le 1$ ,  $0 < y \le 1$ ,  $0 < x + y \le 1$ ) is GaN (is capable of being GaN in view of [0003]).

Regarding claim 23, Bour et al. discloses wherein x in the In-rich region of the quantum well layer is equal to or less than 0.7[0003][0041][0045].

## Claim Rejections - 35 USC § 103

- 4. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 5. Claim 13 is rejected under 35 U.S.C. 103(a) as being unpatentable over Bour (US Pub no. 2003/0020085 A1) in view of Yamada (US Pub no. 2003/0209704 A1).

Regarding claim 13, Bour et al. discloses all the claim limitations of claim 11 but fails to teach wherein the quantum well layer is grown using an In source and a nitrogen source, and the thickness of the quantum well is reduced by growth interruption

which is performed by supplying the nitrogen source with the supply of the In source intercepted to flatten the surface of the quantum well layer.

However, Yamada et al. teaches the quantum well layer having a flattened surface [0030]. It would lt would have been obvious to one of ordinary skill in the art at the time of the invention to modify the semiconductor light emitting device of Nakamura et al. with the quantum well layer having a flattened surface taught by Yamada et al. since doing so improves luminous efficiency. The limitations: grown using an In source and a nitrogen source, and the thickness of the quantum well is reduced by growth interruption which is performed by supplying the nitrogen source with the supply of the In source intercepted are not given patentable weight. "Even though product -by[-] process claims are limited by and defined by the process, determination of patentability is based upon the product itself. The patentability of a product does not depend on its method of production. If the product in product-by-process claim is the same as or obvious from a product of the prior art, the claim is unpatentable even though the prior product is made by a different process." In re Thorpe, 227 USPQ 964,966 (Fed. Cir. 1985)(citations omitted). A "product by process" claim is directed to the product per se, no matter how actually made, In re Hirao and Sato et al., 190 USPQ 15 at 17 (CCPA 1976) (footnote 3). See also In re Brown and Saffer, 173 USPQ 685 (CCPA 1972): In re Luck and Gainer, 177 USPQ 523 (CCPA 1973); In re Fessmann, 180 USPQ 324 (CCPA 1974); and In re Marosi et al., 218 USPQ 289 (CAFC 1983) final product per se which must be determined in a "product by, all of" claim, and not the patentability of the process, and that an old or obvious product, whether claimed in "product by process"

Application/Control Number: 10/596,126 Page 7

Art Unit: 2813

claims or not. Note that Applicant has the burden of proof in such cases, as the above case law makes clear.

### Response to Arguments

6. Applicant's arguments, see remarks, filed 08/03/2009, with respect to claims 11-15,17-23have been fully considered and are persuasive. The rejection has been withdrawn.

### Communication

Any inquiry concerning this communication or earlier communications from the examiner should be directed to LATANYA CRAWFORD whose telephone number is (571)270-3208. The examiner can normally be reached on Monday-Friday 7:30 AM - 5:00 PM EST.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Matthew Landau can be reached on (571)-272-1731. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Application/Control Number: 10/596,126 Page 8

Art Unit: 2813

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

/LaTanya Crawford/ Examiner, Art Unit 2813

/W. David Coleman/ Primary Examiner, Art Unit 2823